

(C-019-D) DC-DC Phase-Shift Full-Bridge Buck Converter (Discrete)

Simulation Parameters (Dialog)

Name	Content	unit	Default Value	Variable Range
Transformer	Np: Primary-turns	turns	10	1 ~ 1000
	Ns: Secondary-turns	turns	9	1 ~ 1000
	Lm: Magnetizing Inductance	H	1m	1n~1
Lr	Leakage Inductance	H	6.8u	1n ~ 1
Lout	Output Inductance	H	330u	1n ~ 1
Cout	Output Capacitance	F	47u	1n ~ 1
Vc_init	Initial Voltage of Cout	V	300	0 ~ 1200
Rp	Parasitic Resistance (Primary)	ohm	5m	1n ~ 100
Rs	Parasitic Resistance (Secondary)	ohm	5m	1n ~ 100
Primary	Thcap_Primary	Thermal Capacitance	J/K	0.1 ~ 100
	Rth_Primary	Thermal Resistance	K/W	0.3 ~ 100
	TGND_Primary	Thermal GND Temperature	°C	-40 ~ 175
Secondary	Thcap_Secondary	Thermal Capacitance	J/K	0.1 ~ 100
	Rth_Secondary	Thermal Resistance	K/W	0.3 ~ 100
	TGND_Secondary	Thermal GND Temperature	°C	-40 ~ 175

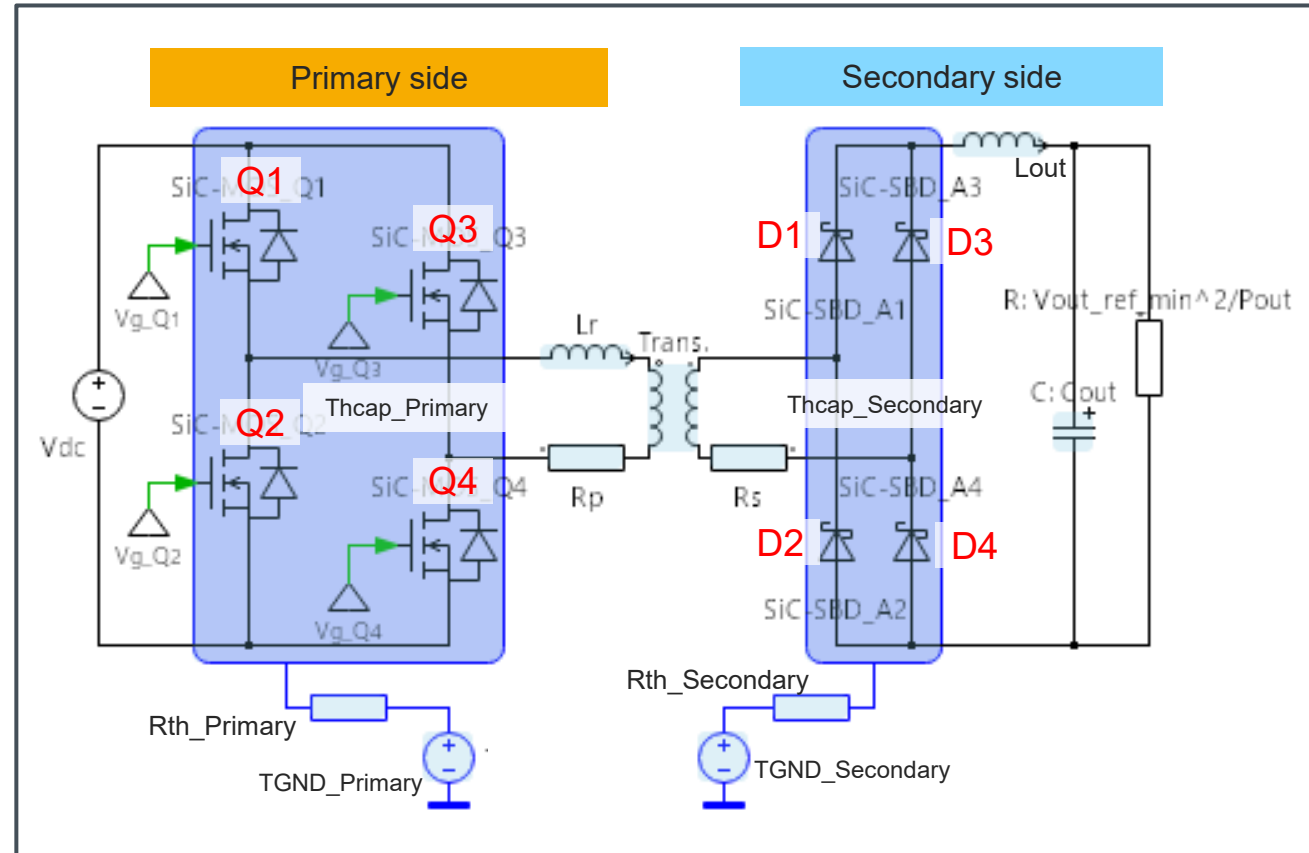
Simulation Parameters (Table)

Name	Content	unit	Default Value	Variable Range
Test_time	Test time in simulation	s	0.2	100u ~ 0.5
fs	Switching Frequency	Hz	30k	10k ~ 100k
Vin	Input Voltage	V	400	100 ~ 1200
Vout_ref_min	Output Voltage	V	300	10 ~ 1200
Vout_ref_max			320	
Pout	Output Power	W	5000	100 ~ 10000
Rg_on*	Gate Resistance (Source)	Ω	6.8	0.1 ~ 100
Rg_off*	Gate Resistance (Sink)	Ω	6.8	0.1 ~ 100
DT	Dead Time	s	100n	0 ~ 1m
T_init**	Initial Junction Temp.	°C	25	-40 ~ 175

*Common for all MOSFETs

**Common for all devices

Simulation Circuit



Default Devices

Name	Device Type	Part No.	Specification
Q1~4	SiC MOSFET	SCT4036DR	750V/ 42A/ 13mΩ/ TO-247-4L
D1~4	SiC SBD***	SCS320AG	650V/ 20A/ TO-220ACGE

*** SBD: Schottky Barrier Diode

Schematic window

- Dialog parameters setting
- Results display

Waveforms

Device selection

Table parameters setting

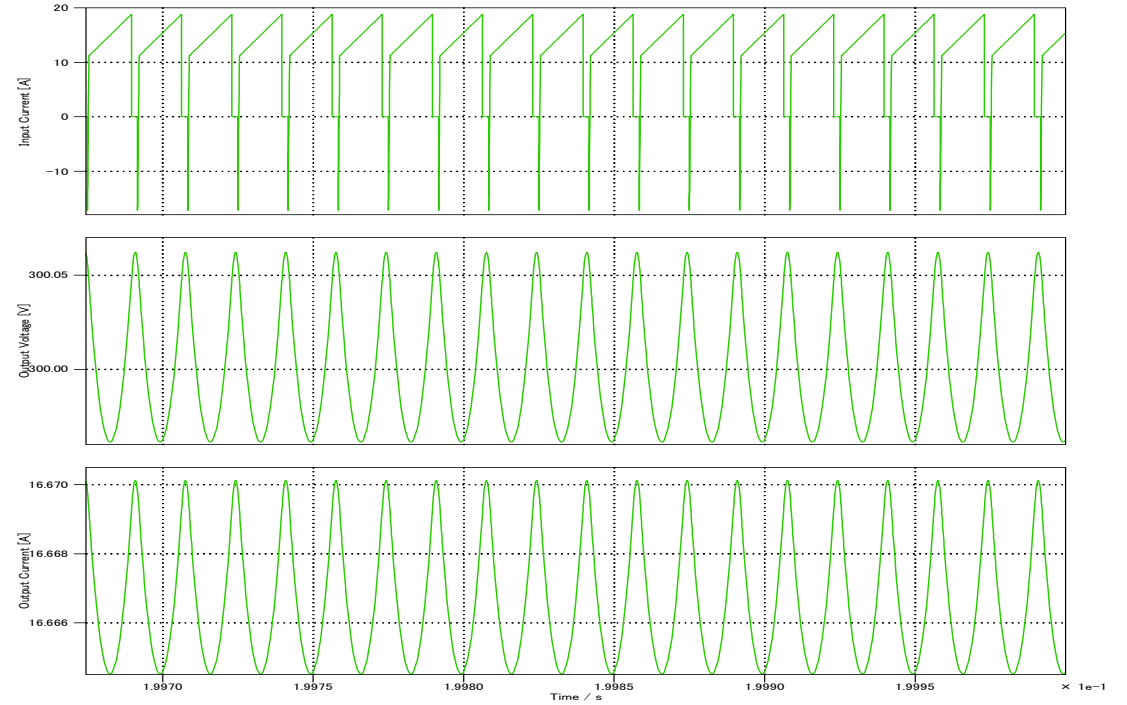
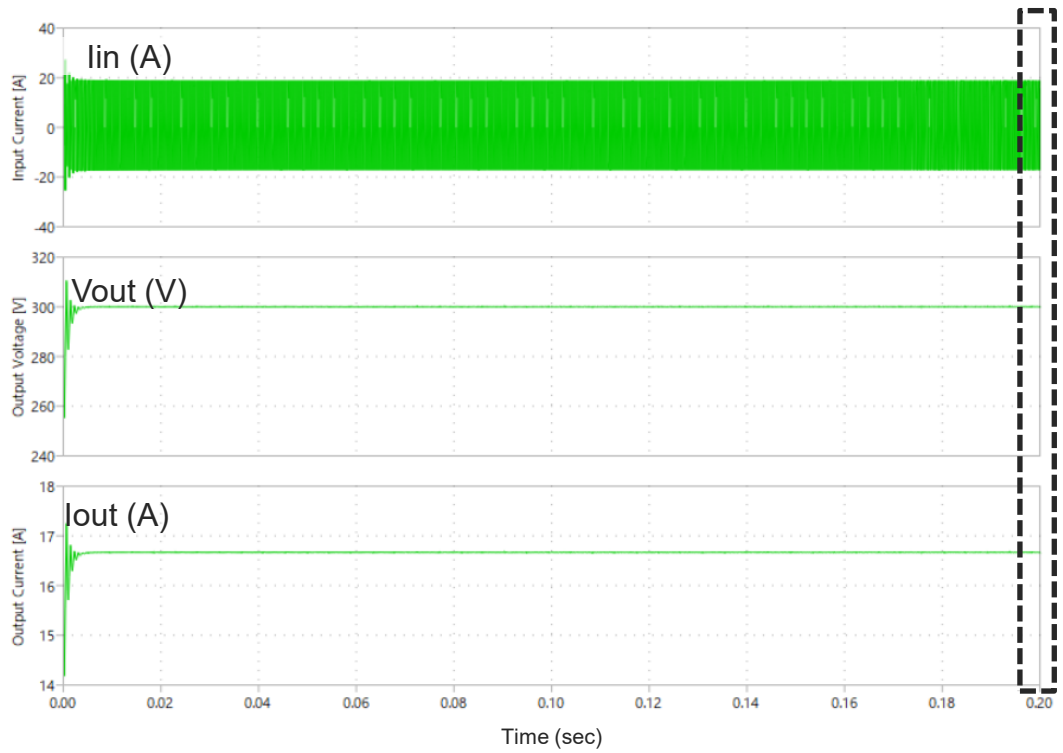
Simulation control

Trace selection

The screenshot displays the ROHM PLECS Simulator interface, which is divided into several functional areas:

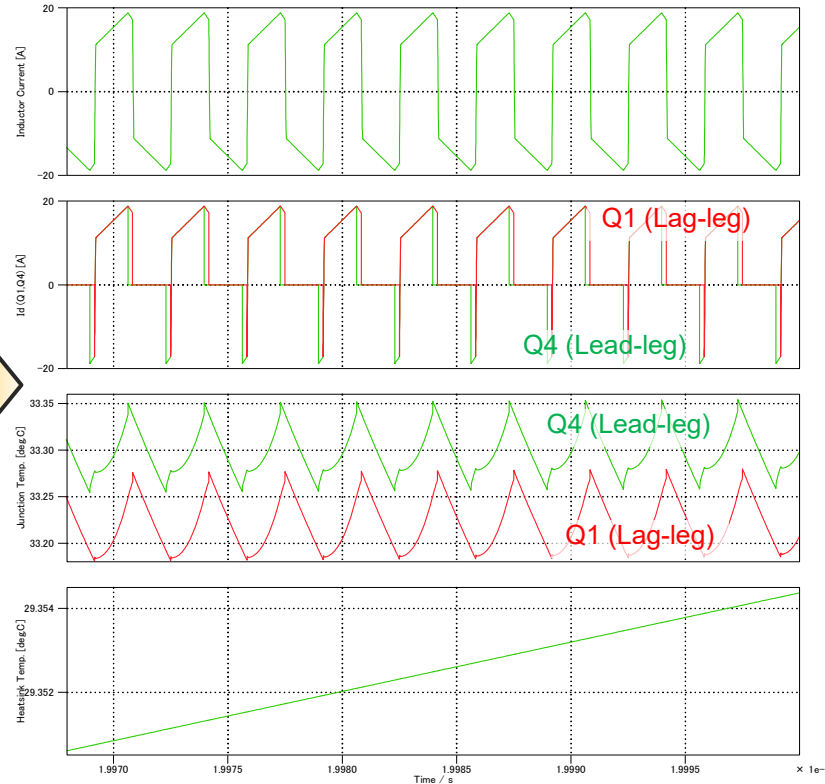
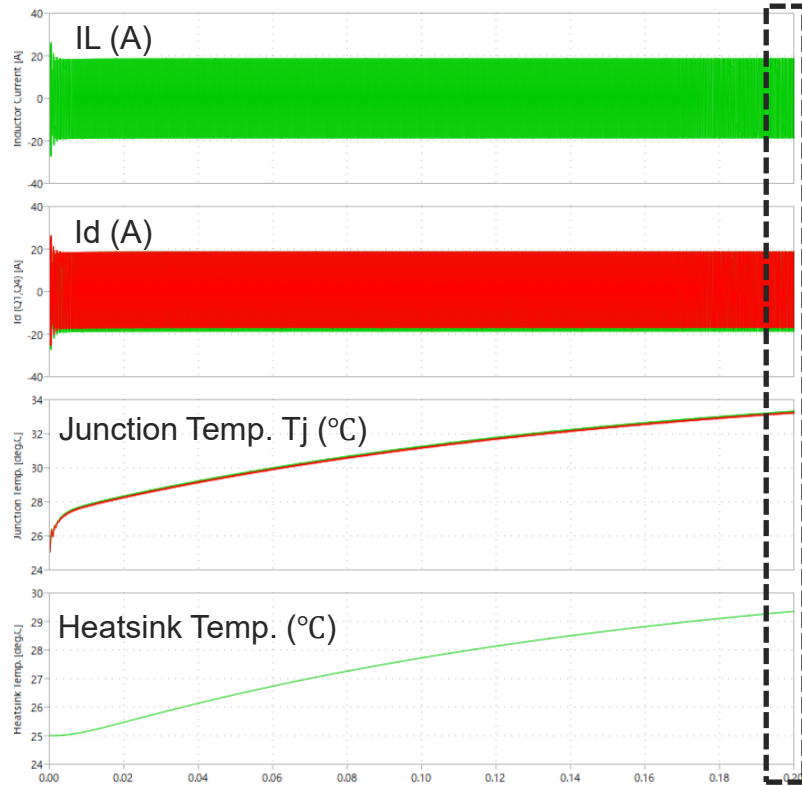
- Schematic Window (Top Left):** Shows a power electronic circuit diagram with components like MOSFETs, diodes, and inductors. It includes an 'Input/Output' table and a 'Secondary Diode' table.
- Waveforms (Top Right):** Displays multiple plots over a 0.20s time interval. The top plot shows 'Input Current [A]' as a green shaded area. Below it are plots for 'Output Voltage [V]', 'Output Current [A]', and 'Primary MOSFET' current.
- Device Selection (Middle Left):** A list of available components for the 'Primary SIC-MOSFET' and 'Secondary SIC-Schottky Barrier Diode'.
- Table Parameters Setting (Bottom Left):** A table for 'Device Conditions' with parameters like $R_{\theta jn}$, $R_{\theta jc}$, and Initial Junction Temperature.
- Simulation Control (Bottom Left):** Buttons for 'Start-Up', 'Steady-state', and 'Hold Result', along with a 'Simulation Completed' indicator.
- Trace Selection (Bottom Left):** A list of active simulation traces.

Input and Output



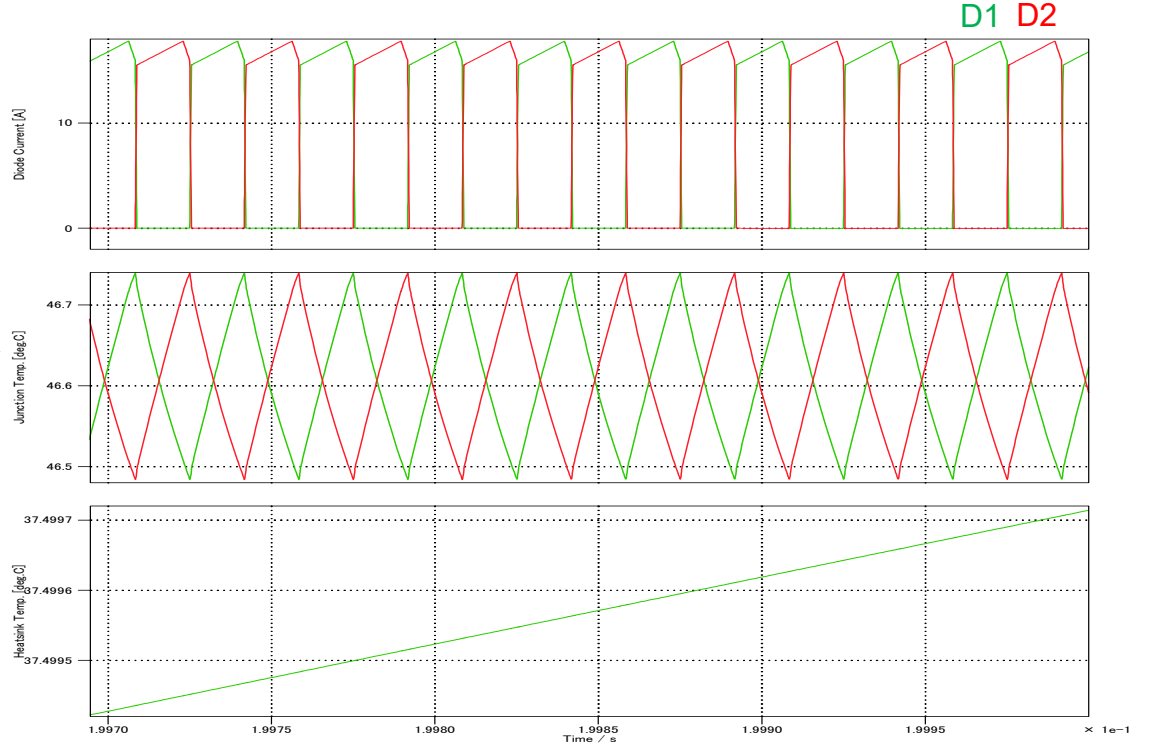
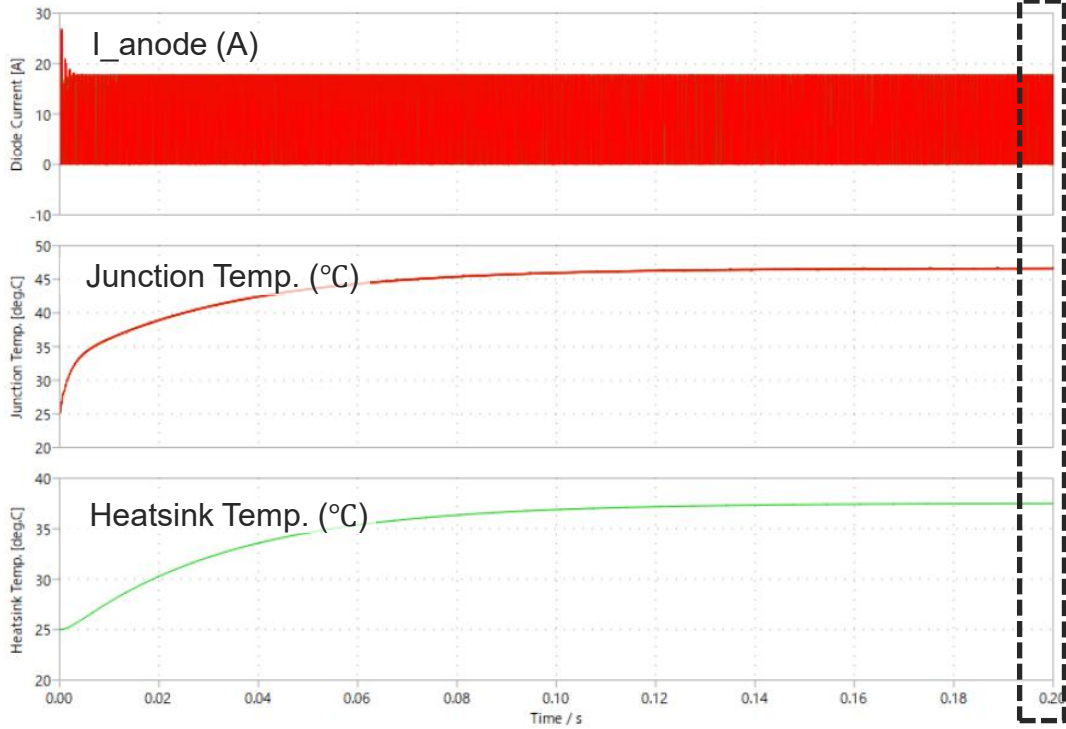
Contents	Results
Input Power : Pin	5.066 (kW)
Output Power: Pout	5.000 (kW)
Efficiency: η	98.69 (%)

Primary side



	Contents	Results
Q4 (Lead-leg)	Conduction Loss: Pcond (Q4)	4.89 (W/device)
	Switching Loss: Psw (Q4)	0.69 (W/device)
	Junction Temp. : Tj (Q4)	33.88 (°C)
Q1 (Lag-leg)	Conduction Loss: Pcond (Q1)	4.85 (W/device)
	Switching Loss: Psw (Q1)	0.69 (W/device)
	Junction Temp. : Tj (Q1)	33.88 (°C)
	Heatsink Temp.: T_hs (primary)	29.65 (°C)
	Total Loss: Ptot (primary)	22.08 (W)

Secondary side

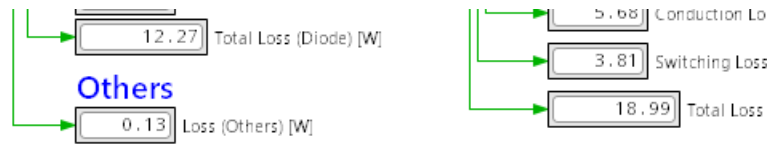


Contents	Results
Junction Temp. T _j (secondary D1,D2)	46.61 (°C)
Heatsink Temp. T _{hs} (secondary)	37.50 (°C)
Total Loss: P _{tot} (secondary)	41.77 (W)

How to change the devices

The figure of "(A-011-D) DC-AC Totem-Pole PFC Diode Rectification (Discrete)" is used as an example in this page.

Device Selection



Device Selection

Parameter	Value
Part No. (SiC-MOSFET)	SCT4065DR (750V/65mΩ/TO-...
Part No. (SiC-Schottky Barrier Diode)	SCS320AG (650V/20A/TO-220...



Device Selection

Part No. (SiC-MOSFET)	SCT4065DR (750V/65mΩ/TO-...
Part No. (SiC-Schottky Barrier Diode)	SCS320AG (650V/20A/TO-220...

- [SCT4036DWA \(750V/36mΩ/TO-263-7LA\)](#)
- [SCT4045DWA \(750V/45mΩ/TO-263-7LA\)](#)
- [SCT4065DWA \(750V/65mΩ/TO-263-7LA\)](#)
- [SCT4013DLL \(750V/13mΩ/TOLL\)](#)
- [SCT4026DLL \(750V/26mΩ/TOLL\)](#)
- [SCT4036DLL \(750V/36mΩ/TOLL\)](#)
- [SCT4045DLL \(750V/45mΩ/TOLL\)](#)

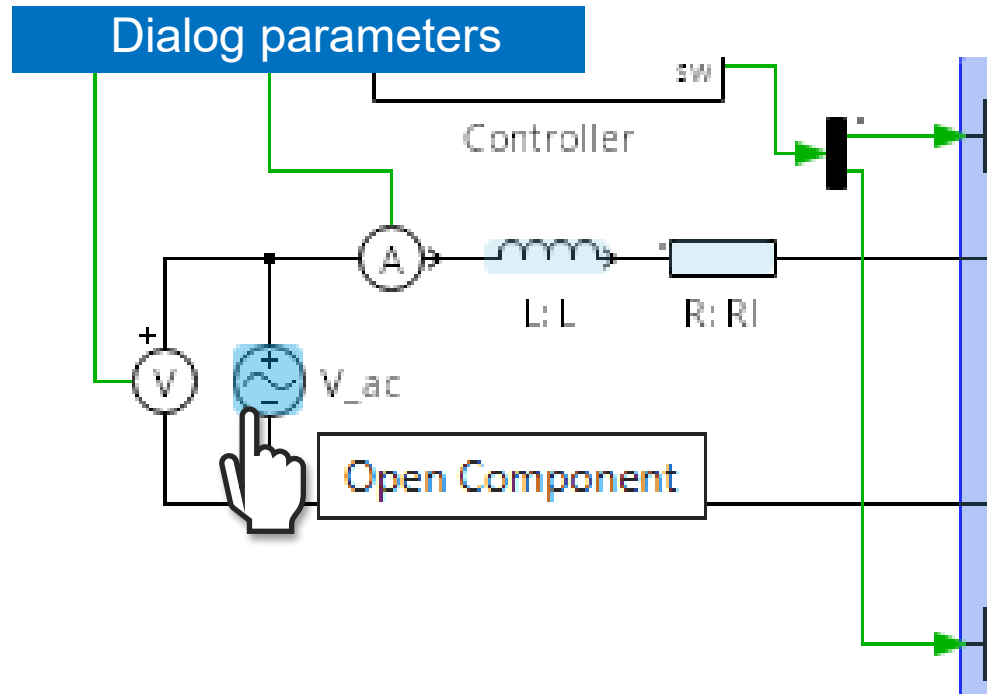
Over your mouse cursor to the device name that you want to change and click the left button of the mouse.

Available device lists are appeared like the above, and you can select a favorite device from these.

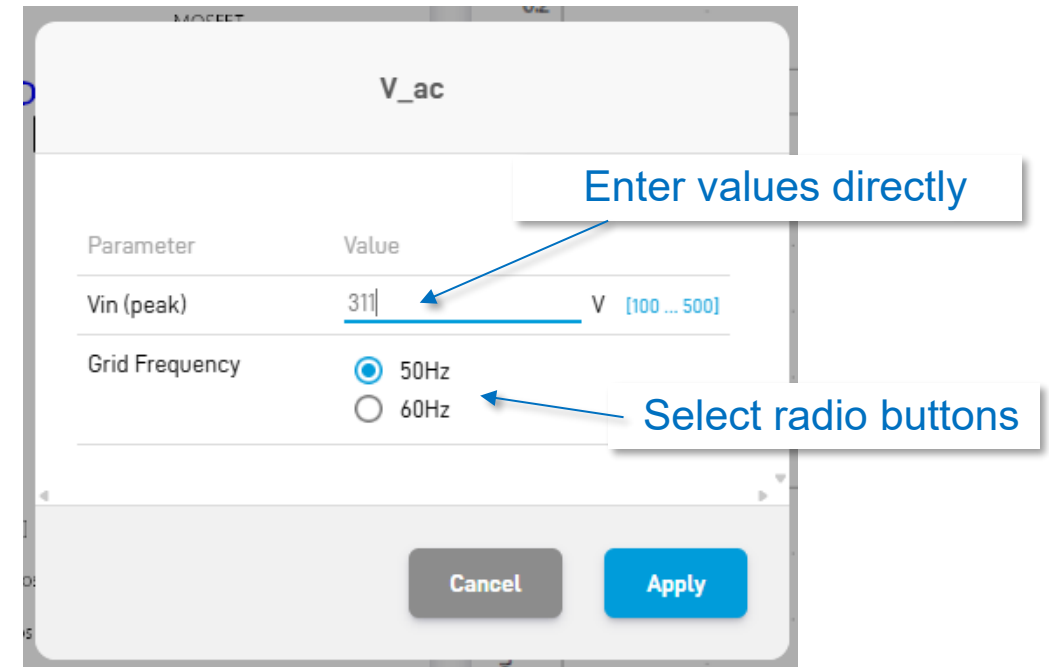
How to change Dialog parameters

The figure of "(A-011-D) DC-AC Totem-Pole PFC Diode Rectification (Discrete)" is used as an example in this page.

- Symbols whose parameters can be changed are colored light-blue in the circuit diagram.
- Over your mouse cursor to the symbol that you want to change the parameter and the symbol color is turned to blue (e.g. "V_ac" symbol in the below).
- Click the mouse's left button.



- A new window like the below is opened.
- You can change the parameters by entering the value directly* or selecting radio buttons.
- Push "Apply" button after changing all parameters.



*Note: Parameters can be entered directly are limited by Min. and Max. values to avoid unexpected system errors.
(e.g. "Vin(peak)" is limited between 100 and 500V in the above.)

How to change Table parameters

The figure of "(A-011-D) DC-AC Totem-Pole PFC Diode Rectification (Discrete)" is used as an example in this page.

ROHM PLECS Simulator
Circuit Information



2026 March
68UG119E Rev.001

Table parameters

General Conditions

Parameter	Value
Test_time	1 sec
Switching Frequency	60000 Hz

Device Conditions

General Conditions

Parameter	Value
Test_time	1 sec
Switching Frequency	<u>20000</u> Hz [10000 ... 100000]

Device Conditions

Choose the parameter that you want change on the parameter tables (e.g. "60kHz" of Switching Frequency in the left figure.)

- A blue under-line and variable range of the parameter are appeared.
- Then, you can change the parameters by entering the value directly " (e.g. "60kHz" was changed to "20kHz").

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